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## Vishay Semiconductors

# **Small Signal Schottky Diode**



#### LINKS TO ADDITIONAL RESOURCES



#### **MECHANICAL DATA**

Case: MiniMELF (SOD-80)
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

#### **FEATURES**





 The LL101 series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring



 The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications

- · Integrated protection ring against static discharge
- Low capacitance
- Low leakage current
- This diode is also available in the DO-35 (DO-204AH) case with type designation SD101A, SD101B, SD101C and in the SOD-123 case with type designation SD101AW, SD101BW, SD101CW
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **APPLICATIONS**

- HF-detector
- Protection circuit
- Diode for low currents wits a low supply voltage
- Small battery charger
- Power supplies
- DC/DC converter for notebooks

PARTS TABLE						
PART	TYPE DIFFERENTIATION	ORDERING CODE	CIRCUIT CONFIGURATION	REMARKS		
LL101A	$V_R = 60 \text{ V}, V_F \text{ at } I_F = 1 \text{ mA max. } 410 \text{ mV}$	LL101A-GS18 or LL101A-GS08	Single	Tape and reel		
LL101B	$V_R = 50 \text{ V}$ , $V_F$ at $I_F = 1 \text{ mA max}$ . 400 mV	LL101B-GS18 or LL101B-GS08	Single	Tape and reel		
LL101C	$V_R = 40 \text{ V}$ , $V_F$ at $I_F = 1 \text{ mA max}$ . 390 mV	LL101C-GS18 or LL101C-GS08	Single	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
		LL101A	$V_{RRM}$	60	V	
Reverse voltage		LL101B	$V_{RRM}$	50	V	
		LL101C	$V_{RRM}$	40	V	
Power dissipation (infinite heatsink) (1)			P <sub>tot</sub>	400	mW	
Forward continuous current			I <sub>F</sub>	30	mA	
Maximum single cycle surge 10 μs square wave			I <sub>FSM</sub>	2	Α	

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature



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THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Junction temperature		Tj	125	°C		
Storage temperature range		T <sub>stg</sub>	-65 to +150	°C		
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R <sub>thJA</sub>	320	K/W		

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I <sub>R</sub> = 10 μA	LL101A	V <sub>(BR)</sub>	60			V
Reverse Breakdown Voltage		LL101B	V <sub>(BR)</sub>	50			V
		LL101C	V <sub>(BR)</sub>	40			V
	V <sub>R</sub> = 50 V	LL101A	I <sub>R</sub>			200	nA
Leakage current	V <sub>R</sub> = 40 V	LL101B	I <sub>R</sub>			200	nA
	V <sub>R</sub> = 30 V	LL101C	I <sub>R</sub>			200	nA
	I <sub>F</sub> = 1 mA	LL101A	V <sub>F</sub>			0.410	V
	I <sub>F</sub> = 1 mA	LL101B	V <sub>F</sub>			0.400	V
Forward voltage drop	I <sub>F</sub> = 1 mA	LL101C	V <sub>F</sub>			0.390	V
Forward voltage drop	I <sub>F</sub> = 15 mA	LL101A	V <sub>F</sub>			1000	mV
		LL101B	$V_{F}$			950	mV
		LL101C	V <sub>F</sub>			900	mV
	V <sub>R</sub> = 0 V, f = 1 MHz	LL101A	C <sub>D</sub>			2.0	pF
Diode capacitance	V 0V f 1MI-	LL101B	C <sub>D</sub>			2.1	pF
	$V_R = 0 V, f = 1 MHz$	LL101C	C <sub>D</sub>			2.2	pF
Reverse recovery time	$I_F = I_R = 5$ mA, recover to 0.1 $I_R$		t <sub>rr</sub>			1	ns

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

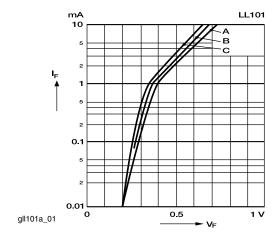


Fig. 1 - Typ.  $I_F$  vs.  $V_F$  for Primary Conduction through the Schottky Barrier

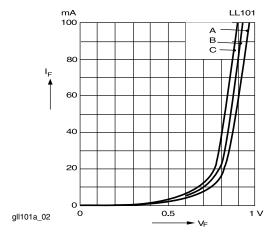


Fig. 2 - Typ.  $I_F$  of Combination Schottky Barrier and PN Junction Guard Ring

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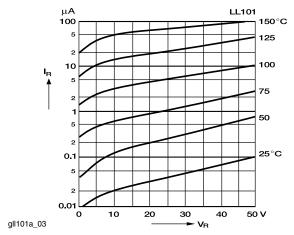


Fig. 3 - Typical Variation of Reverse Current at Various Temperatures

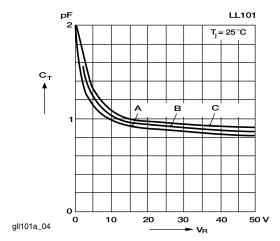
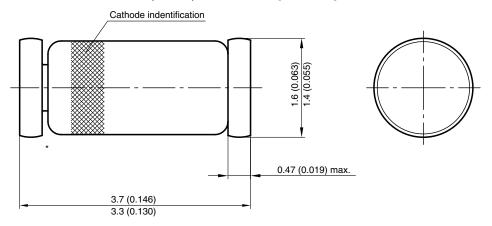
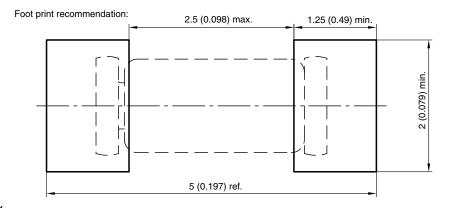


Fig. 4 - Typical Capacitance Curve as a Function of Reverse Voltage

### PACKAGE DIMENSIONS in millimeters (inches): MiniMELF (SOD-80)



<sup>\*</sup> The gap between plug and glass can be either on cathode or anode side



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